

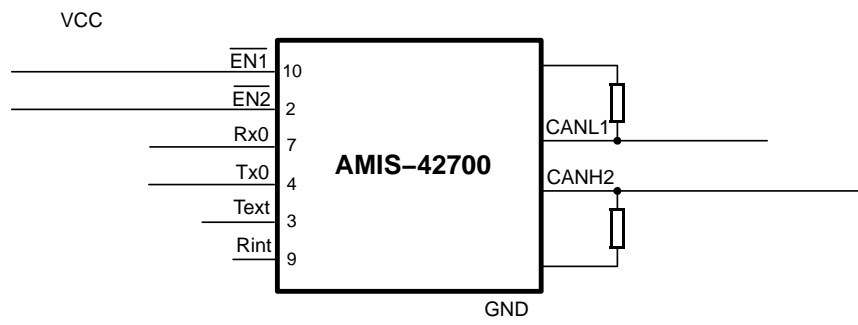
AMIS-42700

Table 1. Technical Characteristics

Symbol	Parameter	Conditions	Min.	Max.	Unit
V_{CANHx}	DC voltage at pin CANH1/2	$0 < V_{CC} < 5.25 \text{ V}$; no time limit	-45	+45	V
V_{CANLx}	DC voltage at pin CANL1/2	$0 < V_{CC} < 5.25 \text{ V}$; no time limit	-45	+45	V
$V_{o(dif)(bus_dom)}$	Differential bus output voltage in dominant state	$42.5 \Omega < R_{LT} < 60 \Omega$	1.5	3	V
CM-range	Input common-mode range for comparator	Guaranteed differential receiver threshold and leakage current			

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VBAT



Functional Description
Overall Functional Description

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Table 3. Function of the Logic Unit (bold letters describe input signals)

EN1B	EN2B	TX0	TEXT	Bus 1 State	Bus 2 State	RX0	RINT
0	1	1	1	recessive	dominant (Note 3)	1	1
1	0	0	0	recessive	dominant	0	0
1	0	0	1	recessive	dominant	0	0
1	0	1	0	recessive	dominant	0	1
1	0	1	1	recessive	recessive	1	1
1	0	1	1	dominant (Note 3)	recessive	1	1
1	0	1	1	recessive	dominant (Note 3)	0	0
1	1	0	0	recessive	recessive	0	0
1	1	0	1	recessive	recessive	0	0
1	1	1	0	recessive	recessive	0	1
1	1	1	1	recessive	recessive	1	1
1	1	1	1	dominant (Note 3)	recessive	1	1
1	1	1	1	recessive	dominant (Note 3)	1	1

3. Dominant detected by the corresponding receiver.

Receivers

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Short Circuits

Reverse Electronic Unit (ECU) Supply

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Faulty Supply

Electrical Characteristics

Definitions

Absolute Maximum Ratings

Table 4. Absolute Maximum Ratings

Symbol	Parameter	Conditions	Min.	Max.	Unit
V_{CC}	Supply voltage		-0.3	+7	V
V_{CANHx}	DC voltage at pin CANH1/2	$0 < V_{CC} < 5.25$ V; no time limit	-45	+45	V
V_{CANLx}	DC voltage at pin CANL1/2	$0 < V_{CC} < 5.25$ V; no time limit	-45	+45	V
V_{digIO}	DC voltage at digital IO pins (EN1B, EN2B,				

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Table 5. Thermal Characteristics

Symbol	Parameter	Conditions	Value	Unit
$R_{th(vj-a)}$	Thermal resistance from junction to ambient in SO20 package	In free air	85	K/W
$R_{th(vj-s)}$	Thermal resistance from junction to substrate of bare die	In free air	45	K/W

Table 6. DC and Timing Characteristics ($V_{CC} = 4.75$ to 5.25 V; $T_{junc} = -40$ to $+150^{\circ}C$; $R_{LT} = 60$ W unless specified otherwise.)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
SUPPLY (pin V_{CC})						
I_{CC}	Supply current, no loads on digital outputs, both busses enabled	Dominant transmitted		45	137.5	
		Recessive transmitted			19.5	

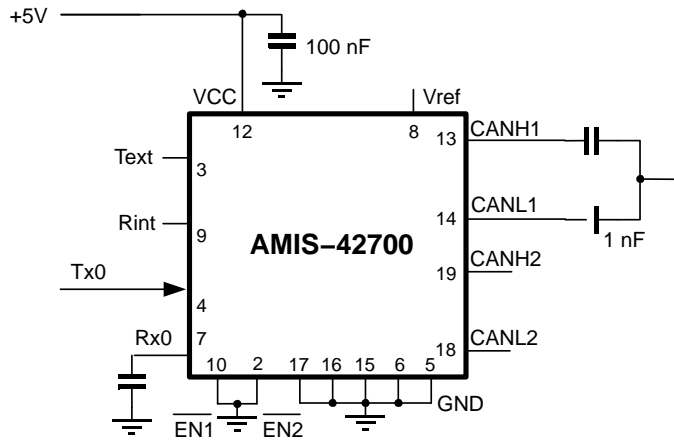
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Table 6. DC and Timing Characteristics ($V_{CC} = 4.75$ to 5.25 V; $T_{junc} = -40$ to $+150^{\circ}\text{C}$; $R_{LT} = 60$ W unless specified otherwise.)

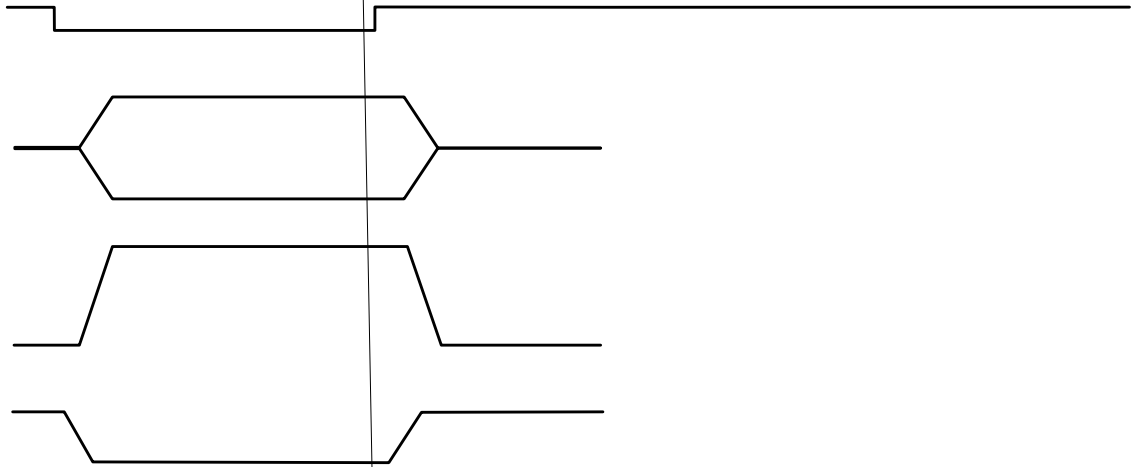
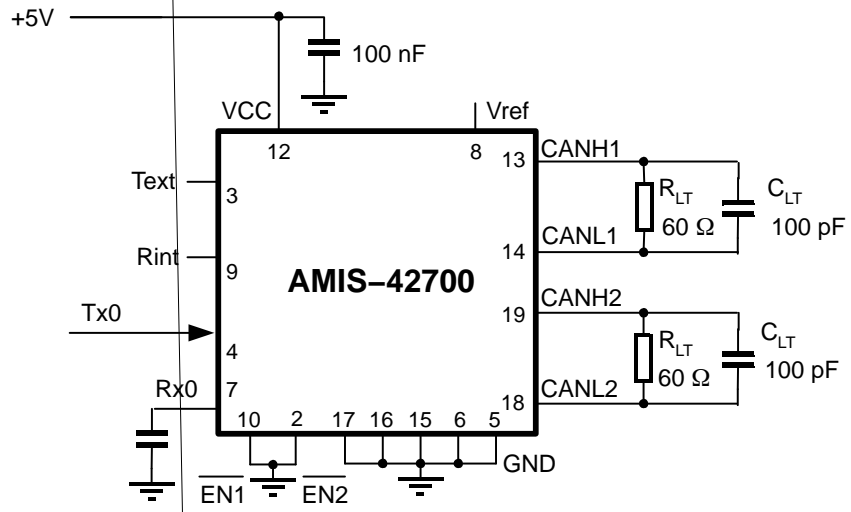
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
BUS LINES (pins CANH1/2 and CANL1/2)						
$V_{i(dif)(th)}$	Differential receiver threshold voltage	$-5\text{ V} < V_{CANLx} < +12\text{ V};$ $-5\text{ V} < V_{CANHx} < +12\text{ V};$ see Figure 6	0.5	0.7	0.9	V
$V_{ihcm(dif)(th)}$	Differential receiver threshold voltage for high common-mode	$-35\text{ V} < V_{CANLx} < +35\text{ V};$ $-35\text{ V} < V_{CANHx} < +35\text{ V};$ see Figure 6	0.3	0.7	1.05	V
$V_{i(dif)(hys)}$	Differential receiver input voltage hysteresis	$-35\text{ V} < V_{CANL} < +35\text{ V};$ $-35\text{ V} < V_{CANH} < +35\text{ V};$ see Figure 6				

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Measurement Set-ups and Definitions



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Soldering

Introduction to Soldering Surface Mount Packages

Re-flow Soldering

Wave Soldering

Manual Soldering

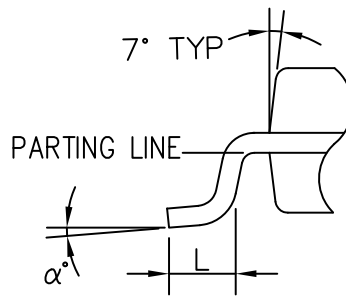
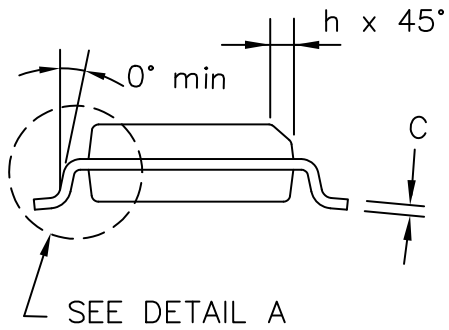
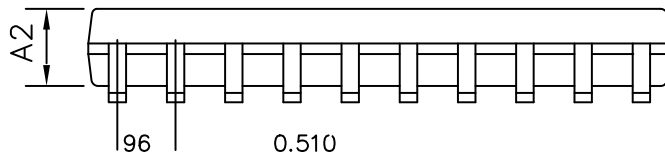
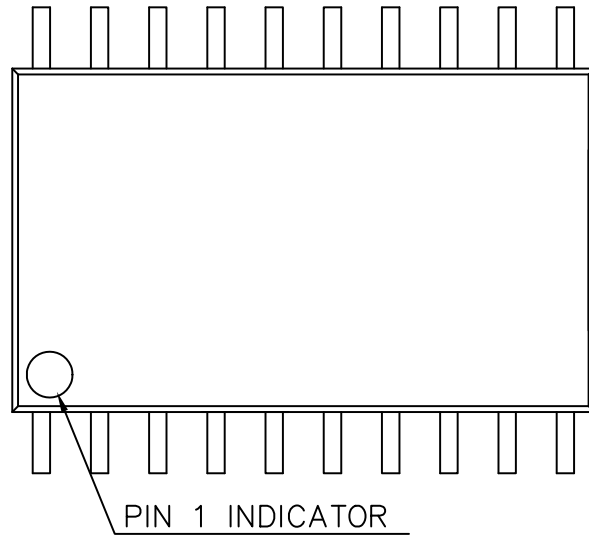
Table 7. Soldering Process

Package	Soldering Method	
	Wave	Re-flow (Note 9)
BGA, SQFP	Not suitable	Suitable
HLQFP, HSQFP, HSOP, HTSSOP, SMS	Not suitable (Note 10)	Suitable
PLCC (Note 11), SO, SOJ	Suitable	Suitable
LQFP, QFP, TQFP	Not recommended (Notes 11 and 12)	Suitable
SSOP, TSSOP, VSO	Not recommended (Note 13)	Suitable

9. All SMD packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body Q.06.t 2.moi90709 refBTin 575.5oards

SOIC 20 W
CASE 751AQ 01
ISSUE O

DATE 19 JUN 2008



DETAIL A

DIMENSIONS IN INCHES		
SYMBOL	NOM	MAX.
A	0.093	0.104
A1		0.012
A2	0.088 0.094	0.100
B		
C	.00	
D		
E	0.292 0.296	0.299
e	.050 BSC.	
H	0.402	0.419
h	0.010 0.015	0.019
L	0.016 0.033	
	0°	5° 8°

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